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Front Matter: Volume 11097

, "Front Matter: Volume 11097," Proc. SPIE 11097, Organic and Hybrid Field-Effect Transistors XVIII, 1109701 (16 October 2019); doi: 10.1117/12.2551099

SPIE.

Event: SPIE Organic Photonics + Electronics, 2019, San Diego, California, United States

PROCEEDINGS OF SPIE

Organic and Hybrid Field-Effect Transistors XVIII

Iain McCulloch
Oana D. Jurchescu
Editors

12–15 August 2019
San Diego, California, United States

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Millipore Sigma (United States)
Journal of Materials Chemistry C (United Kingdom)

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SPIE

Volume 11097

Proceedings of SPIE 0277-786X, V. 11097

SPIE is an international society advancing an interdisciplinary approach to the science and application of light.

Organic and Hybrid Field-Effect Transistors XVIII, edited by Iain McCulloch,
Oana D. Jurchescu, Proc. of SPIE Vol. 11097, 1109701 · © 2019 SPIE
CCC code: 0277-786X/19/\$21 · doi: 10.1117/12.2551099

Proc. of SPIE Vol. 11097 1109701-1

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Author(s), "Title of Paper," in *Organic and Hybrid Field-Effect Transistors XVIII*, edited by Iain McCulloch, Oana D. Jurchescu, Proceedings of SPIE Vol. 11097 (SPIE, Bellingham, WA, 2019) Seven-digit Article CID Number.

ISSN: 0277-786X
ISSN: 1996-756X (electronic)

ISBN: 9781510628878
ISBN: 9781510628885 (electronic)

Published by
SPIE
P.O. Box 10, Bellingham, Washington 98227-0010 USA
Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445
SPIE.org
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